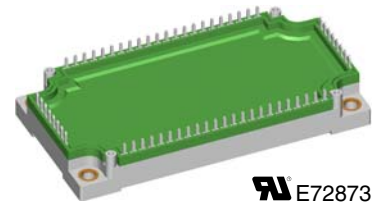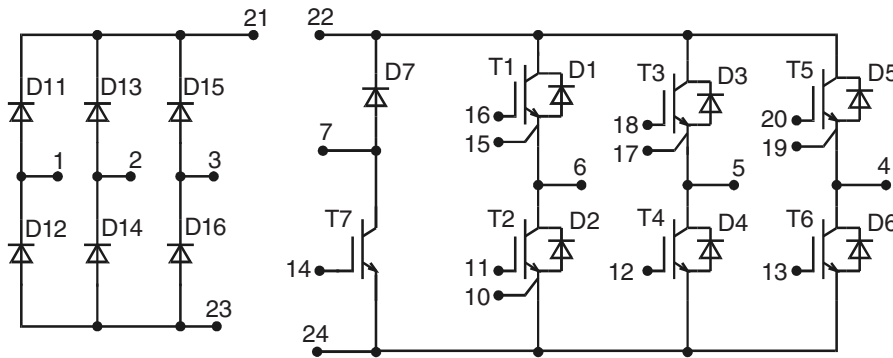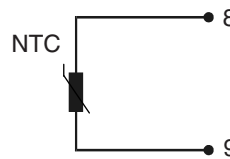# IXYS

Converter - Brake - Inverter Module (CBI3)

U E72873

See outline drawing for pin arrangement

Three Phase Rectifier	Brake Chopper	Three Phase Inverter
V_{RRM} = 1600 V	V_{CES} = 1200 V	V_{CES} = 1200 V
I_{FAVM} = 70 A	I_{C25} = 52 A	I_{C25} = 90 A
I_{FSM} = 700 A	$V_{CE(sat)}$ = 2.2 V	$V_{CE(sat)}$ = 1.9 V

Input Rectifier Bridge D11 - D16

Symbol	Conditions	Maximum Ratings	
V_{RRM}		1600	V
I_{FAV}	T_C = 80°C; sine 180°	50	A
I_{DAVM}	T_C = 80°C; rectangular; d = $^1/_3$; bridge	140	A
I_{FSM}	T_{VJ} = 25°C; t = 10 ms; sine 50 Hz	700	A
P_{tot}	T_C = 25°C	135	W

Symbol	Conditions	Characteristic Values (T_{VJ} = 25°C, unless otherwise specified)			
		min.	typ.	max.	
V_F	I_F = 50 A; T_{VJ} = 25°C		1.1	1.3	V
	T_{VJ} = 125°C		1.1		V
I_R	V_R = V_{RRM}; T_{VJ} = 25°C			0.05	mA
	T_{VJ} = 125°C		0.8		mA
R_{thJC}	(per diode)			0.94	K/W

Application: AC motor drives with

- Input from single or three phase grid
- Three phase synchronous or asynchronous motor
- electric braking operation

Features

- High level of integration - only one power semiconductor module required for the whole drive
- IGBT technology with low saturation voltage, low switching losses and tail current, high RBSOA and short circuit ruggedness
- Epitaxial free wheeling diodes with Hiperfast and soft reverse recovery
- Industry standard package with insulated copper base plate and soldering pins for PCB mounting
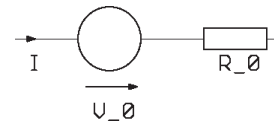- Temperature sense included

IXYS reserves the right to change limits, test conditions and dimensions.

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Output Inverter T1 - T6

Symbol	Conditions		Maximum Ratings	
V_{CES}	T_{VJ} = 25°C to 150°C		1200	V
V_{GES}	Continuous		± 20	V
I_{C25}	T_C = 25°C		90	A
I_{C80}	T_C = 80°C		62	A
I_{CM}	V_{GE} = ±15 V; R_G = 22 Ω; T_{VJ} = 125°C		100	A
V_{CEK}	RBSOA; Clamped inductive load; L = 100 µH		V_{CES}	
t_{SC} (SCSOA)	V_{CE} = 900 V; V_{GE} = ±15 V; R_G = 22 Ω; T_{VJ} = 125°C non-repetitive		10	µs
P_{tot}	T_C = 25°C		350	W

Symbol	Conditions	Characteristic Values (T_{VJ} = 25°C, unless otherwise specified)			
		min.	typ.	max.	
$V_{CE(sat)}$	I_C = 50 A; V_{GE} = 15 V; T_{VJ} = 25°C		1.9	2.4	V
	T_{VJ} = 125°C		2.1		V
$V_{GE(th)}$	I_C = 2 mA; V_{GE} = V_{CE}	4.5		6.5	V
I_{CES}	V_{CE} = V_{CES}; V_{GE} = 0 V; T_{VJ} = 25°C			0.8	mA
	T_{VJ} = 125°C		0.8		mA
I_{GES}	V_{CE} = 0 V; V_{GE} = ± 20 V			200	nA
$t_{d(on)}$			80		ns
t_r	Inductive load, T_{VJ} = 125°C		50		ns
$t_{d(off)}$	V_{CE} = 600 V; I_C = 50 A		680		ns
t_f	V_{GE} = ±15 V; R_G = 22 Ω		30		ns
E_{on}			6		mJ
E_{off}			4		mJ
C_{ies}	V_{CE} = 25 V; V_{GE} = 0 V; f = 1 MHz		3.8		nF
Q_{Gon}	V_{CE} = 600 V; V_{GE} = 15 V; I_C = 50 A		350		nC
R_{thJC}	(per IGBT)			0.35	K/W

Equivalent Circuits for Simulation

Conduction

IGBT (typ. at V_{GE} = 15 V; T_J = 125°C)
T1-T6
V_0 = 0.98 V; R_0 = 23.2 mΩ
T7
V_0 = 0.95 V; R_0 = 45 mΩ

Diode (typ. at T_J = 125°C)
D1-D6
V_0 = 1.27 V; R_0 = 5.8 mΩ
D7
V_0 = 1.25 V; R_0 = 31.2 mΩ
D11-D16
V_0 = 0.83 V; R_0 = 5.5 mΩ

Output Inverter D1 - D6

Symbol	Conditions		Maximum Ratings	
I_{F25}	T_C = 25°C		110	A
I_{F80}	T_C = 80°C		70	A

Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	
V_F	I_F = 50 A; V_{GE} = 0 V; T_{VJ} = 25°C		2.1	2.5	V
	T_{VJ} = 125°C		1.5		V
I_{RM}	I_F = 60 A; di_F/dt = -500 A/µs; T_{VJ} = 125°C		41		A
t_{rr}	V_R = 600 V; V_{GE} = 0 V		200		ns
R_{thJC}	(per diode)			0.61	K/W

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Brake Chopper T7

Symbol	Conditions	Maximum Ratings	
V_{CES}	T_{VJ} = 25°C to 150°C	1200	V
V_{GES}	Continuous	± 20	V
I_{C25}	T_C = 25°C	52	A
I_{C80}	T_C = 80°C	35	A
I_{CM}	V_{GE} = ±15 V; R_G = 39 Ω; T_{VJ} = 125°C	50	A
V_{CEK}	RBSOA; Clamped inductive load; L = 100 µH	V_{CES}	
t_{SC} (SCSOA)	V_{CE} = 900 V; V_{GE} = ±15 V; R_G = 39 Ω; T_{VJ} = 125°C non-repetitive	10	µs
P_{tot}	T_C = 25°C	225	W

Symbol	Conditions	Characteristic Values (T_{VJ} = 25°C, unless otherwise specified)			
		min.	typ.	max.	
$V_{CE(sat)}$	I_C = 35 A; V_{GE} = 15 V; T_{VJ} = 25°C		2.2	2.8	V
	T_{VJ} = 125°C		2.5		V
$V_{GE(th)}$	I_C = 1 mA; V_{GE} = V_{CE}	4.5		6.5	V
I_{CES}	V_{CE} = V_{CES}; V_{GE} = 0 V; T_{VJ} = 25°C			0.1	mA
	T_{VJ} = 125°C		0.1		mA
I_{GES}	V_{CE} = 0 V; V_{GE} = ± 20 V			200	nA
$t_{d(on)}$			85		ns
t_r	Inductive load, T_{VJ} = 125°C		50		ns
$t_{d(off)}$	V_{CE} = 600 V; I_C = 35 A		440		ns
t_f	V_{GE} = ±15 V; R_G = 39 Ω		50		ns
E_{off}			2.6		mJ
C_{ies}	V_{CE} = 25 V; V_{GE} = 0 V; f = 1 MH z		2		nF
Q_{Gon}	V_{CE}= 600 V; V_{GE} = 15 V; I_C = 35 A		150		nC
R_{thJC}				0.55	K/W

Brake Chopper D7

Symbol	Conditions	Maximum Ratings	
V_{RRM}	T_{VJ} = 25°C to 150°C	1200	V
I_{F25}	T_C = 25°C	25	A
I_{F80}	T_C = 80°C	16	A

Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	
V_F	I_F = 35 A; T_{VJ} = 25°C		3.0	3.4	V
	T_{VJ} = 125°C		2.3		V
I_R	V_R = V_{RRM}; T_{VJ} = 25°C			0.1	mA
	T_{VJ} = 125°C		0.1		mA
I_{RM}	I_F = 15 A; di_F/dt = -400 A/µs; T_{VJ} = 125°C		16		A
t_{rr}	V_R = 600 V		130		ns
R_{thJC}				2.1	K/W

PHASE-OUT

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Temperature Sensor NTC

Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	
R_{25}	T = 25°C	4.75	5.0	5.25	kΩ
$B_{25/50}$			3375		K

Module

Symbol	Conditions	Maximum Ratings	
T_{VJ}	operating	-40...+125	°C
T_{JM}		150	°C
T_{stg}		-40...+125	°C
V_{ISOL}	$I_{ISOL} \leq 1$ mA; 50/60 Hz	2500	V~
M_d	Mounting torque (M5)	3 - 6	Nm

Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	
$R_{pin-chip}$			5		mΩ
d_S	Creepage distance on surface	6			mm
d_A	Strike distance in air	6			mm
R_{thCH}	with heatsink compound		0.01		K/W
Weight			300		g

Dimensions in mm (1 mm = 0.0394")
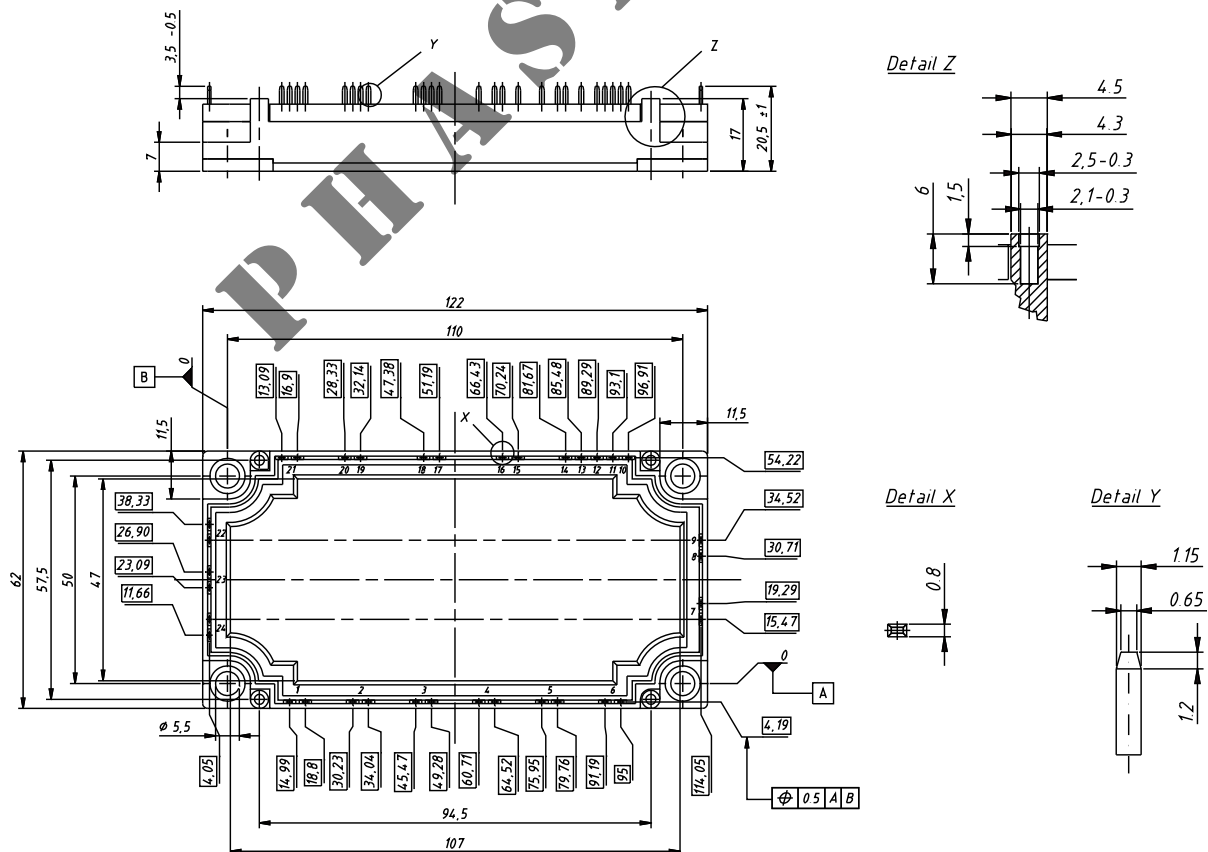
Input Rectifier Bridge D11 - D16
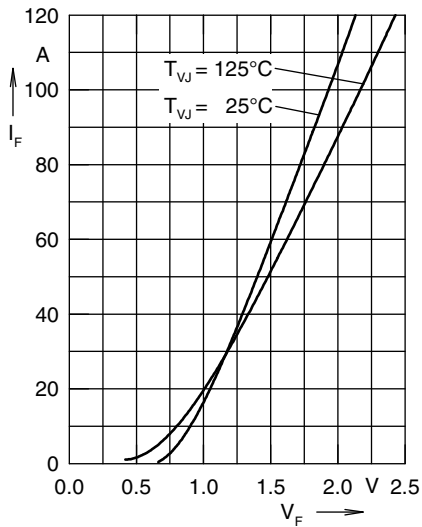
Fig. 1 Forward current versus voltage drop per diode
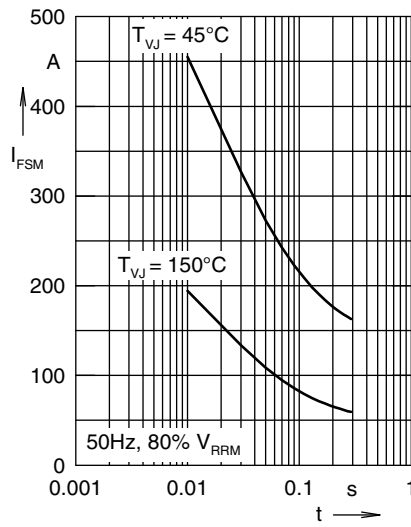
Fig. 2 Surge overload current
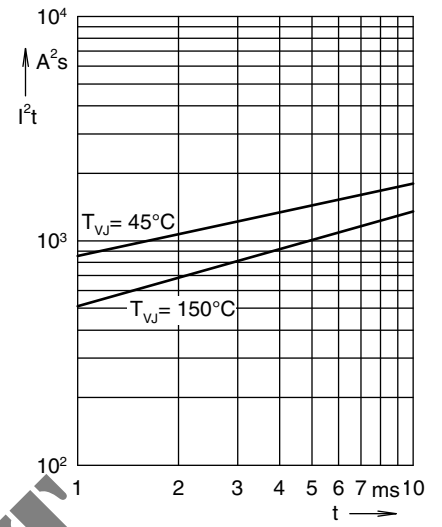
Fig. 3 I²t versus time per diode
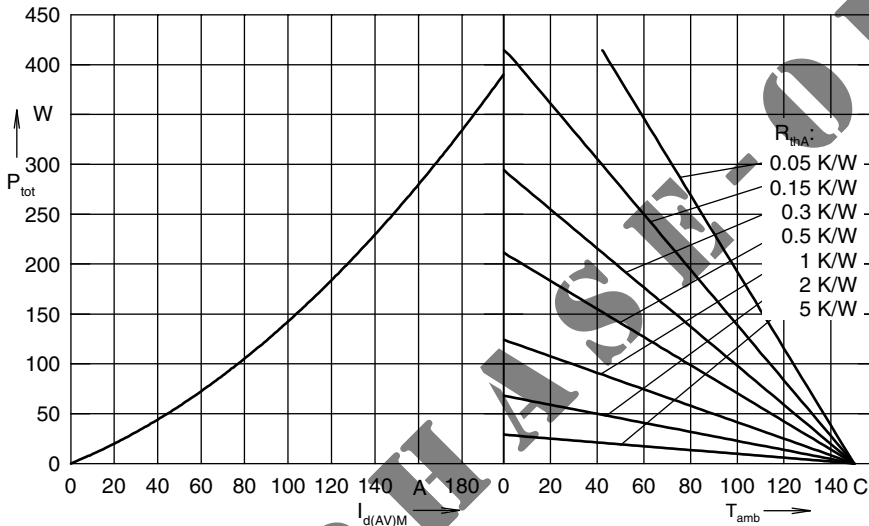
Fig. 4 Power dissipation versus direct output current and ambient temperature, sin 180°
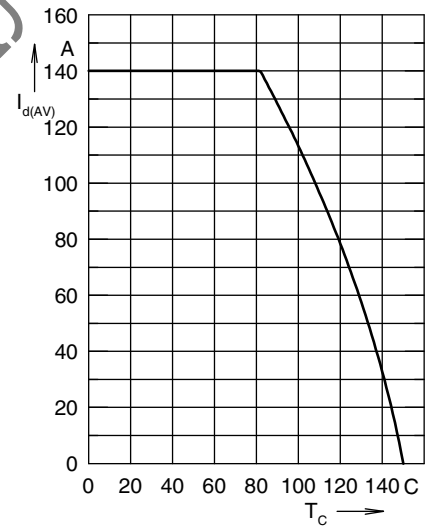
Fig. 5 Max. forward current versus case temperature

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Output Inverter T1 - T6 / D1 - D6
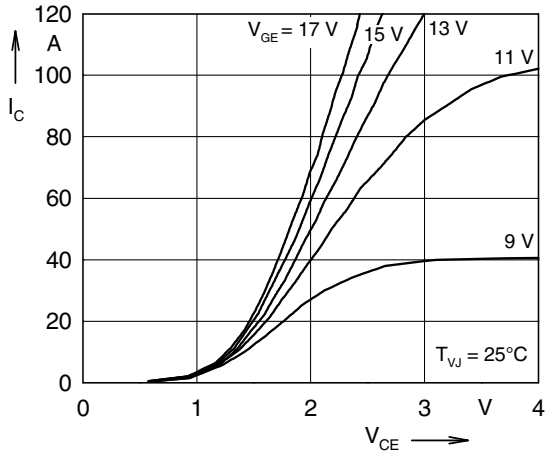
Fig. 7   Typ. output characteristics
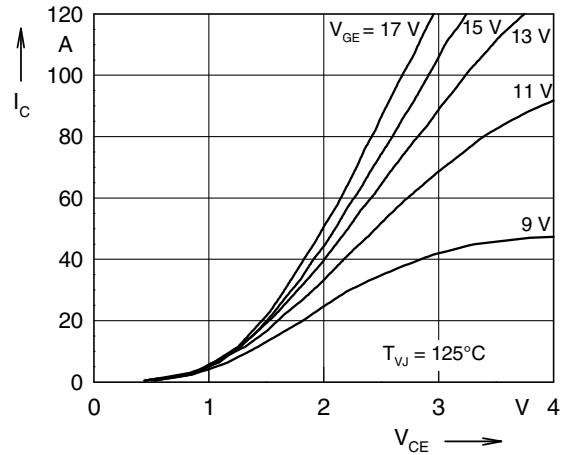
Fig. 8   Typ. output characteristics
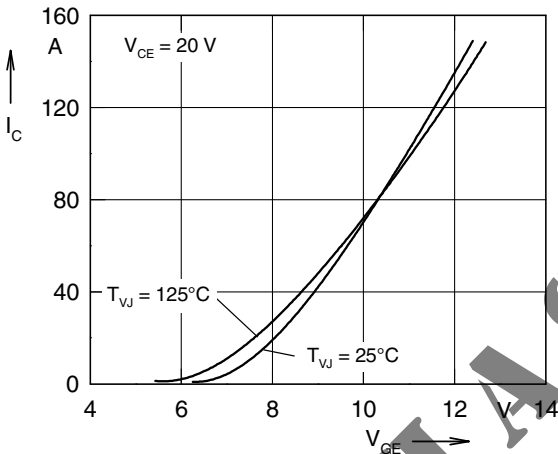
Fig. 9   Typ. transfer characteristics
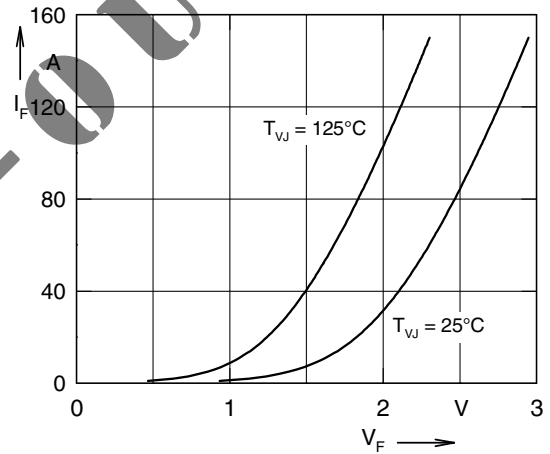
Fig. 10   Typ. forward characteristics of free wheeling diode
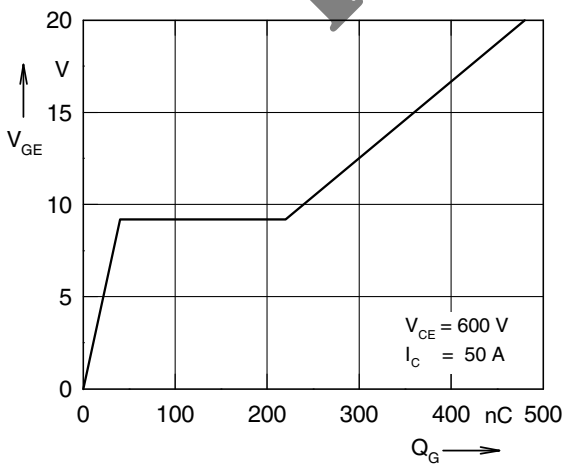
Fig. 11   Typ. turn on gate charge
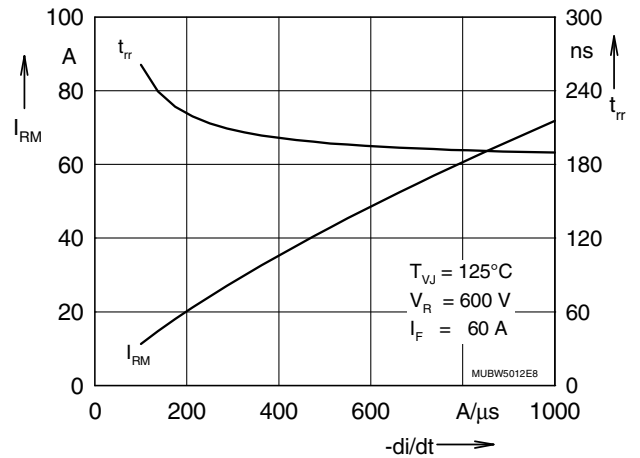
Fig. 12   Typ. turn off characteristics of free wheeling diode

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Output Inverter T1 - T6 / D1 - D6
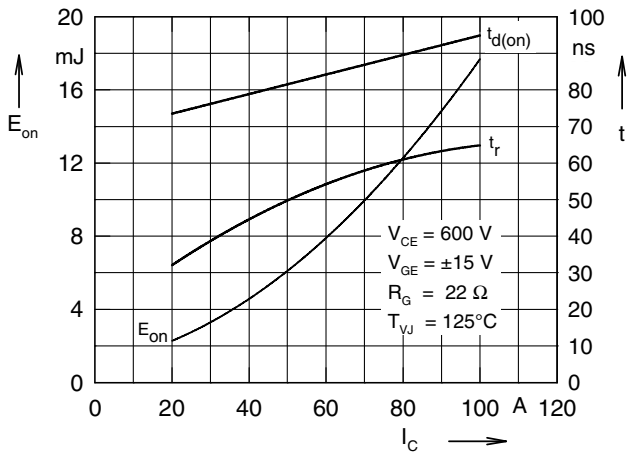
Fig. 13   Typ. turn on energy and switching
            times versus collector current
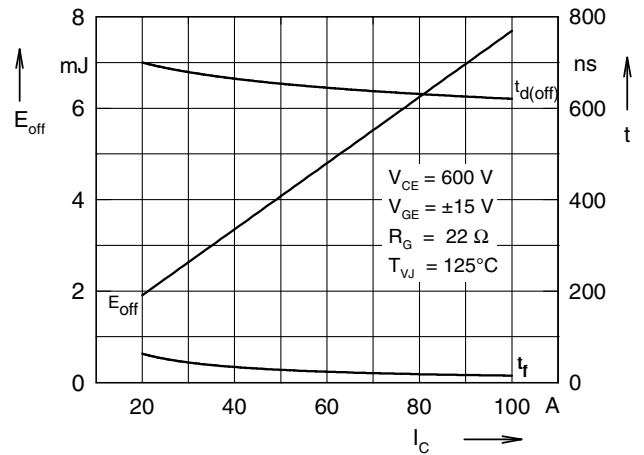
Fig. 14   Typ. turn off energy and switching
            times versus collector current
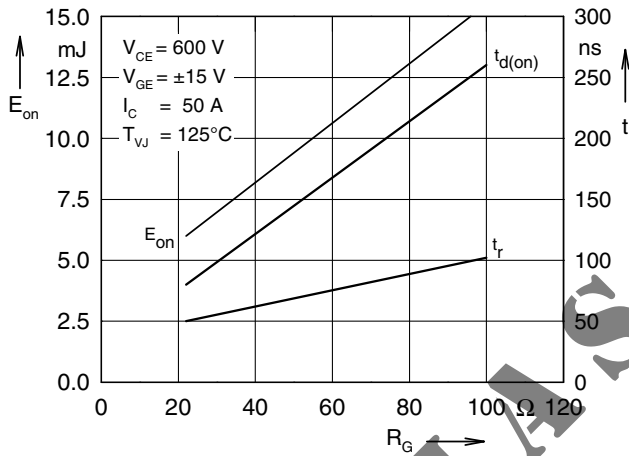
Fig. 15 Typ. turn on energy and switching
            times versus gate resistor
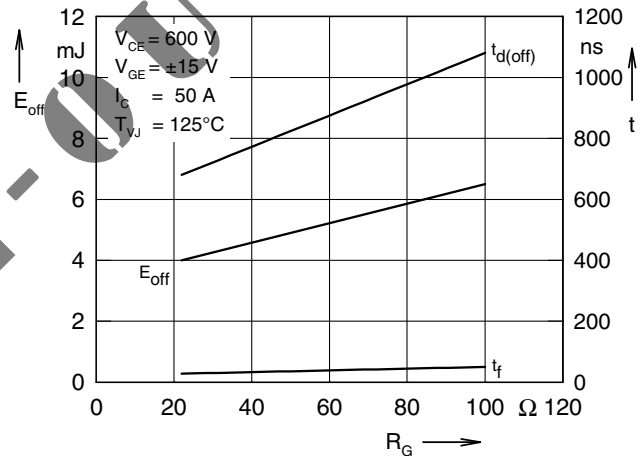
Fig.16   Typ. turn off energy and switching
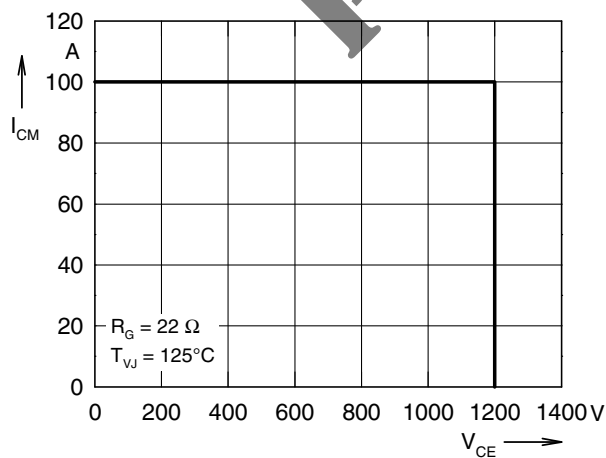   times versus gate resistor

Fig. 17   Reverse biased safe operating area
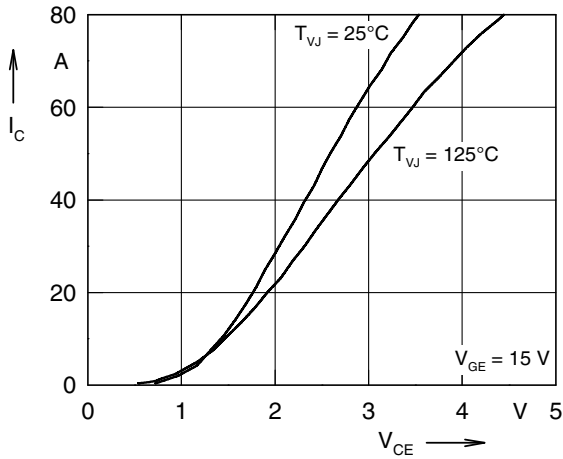   RBSOA

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Brake Chopper T7 / D7

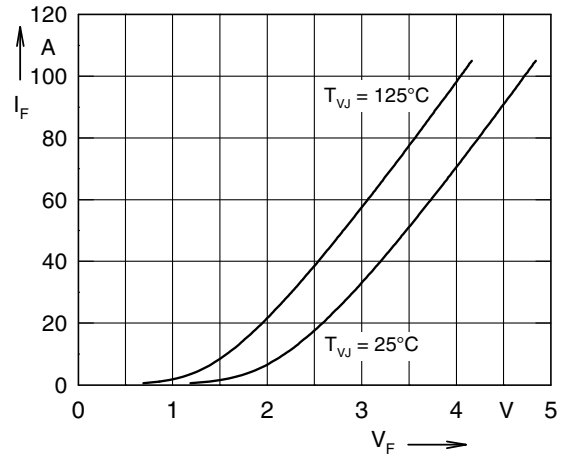Fig. 19   Typ. output characteristics

Fig. 20   Typ. forward characteristics of free wheeling diode
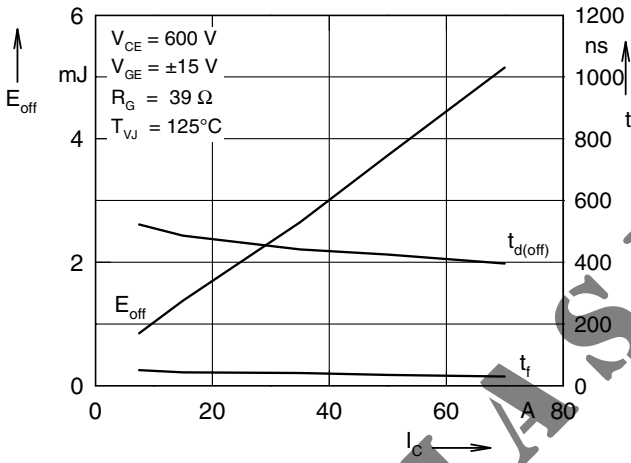

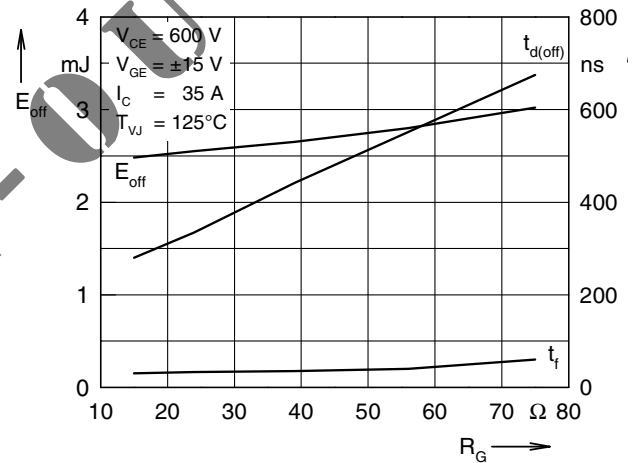Fig. 21   Typ. turn off energy and switching times versus collector current

Fig. 22   Typ. turn off energy and switching times versus gate resistor
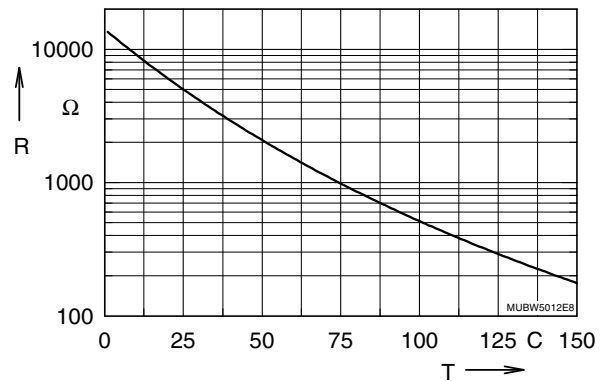
Temperature Sensor NTC

Fig. 24   Typ. thermistorresistance versus temperature

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